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CPH6445

N-Channel Power MOSFET 60V, 3.5A, 117mΩ, Single CPH6

Features

- 4V drive
- Low ON-resistance
- Protection diode in

Specifications

Absolute Maximum Ratings at Ta=25°C

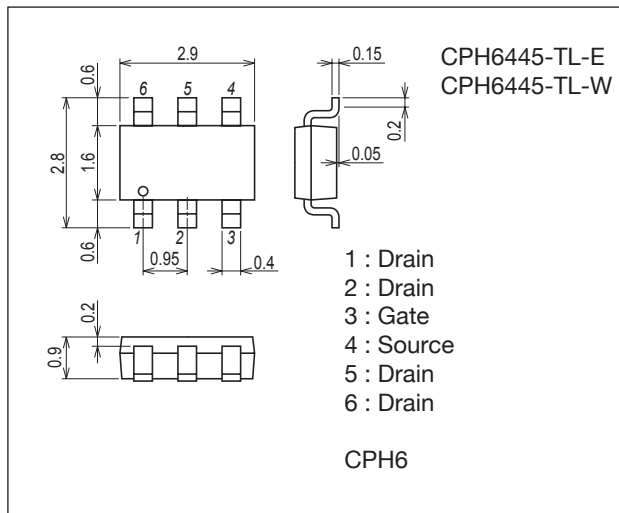
Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V _{DSS}		60	V
Gate-to-Source Voltage	V _{GSS}		±20	V
Drain Current (DC)	I _D		3.5	A
Drain Current (Pulse)	I _{DP}	PW≤10μs, duty cycle≤1%	14	A
Allowable Power Dissipation	P _D	When mounted on ceramic substrate (1200mm ² ×0.8mm)	1.6	W
Channel Temperature	T _{ch}		150	°C
Storage Temperature	T _{stg}		-55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

Package Dimensions

unit : mm (typ)

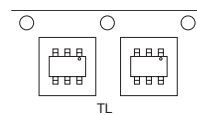
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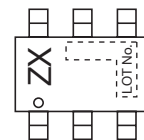
Product & Package Information

- Package : CPH6
- JEITA, JEDEC : SC-74, SOT-26, SOT-457
- Minimum Packing Quantity : 3,000 pcs./reel

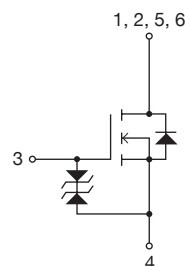
Packing Type: TL



Marking



Electrical Connection



ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet.

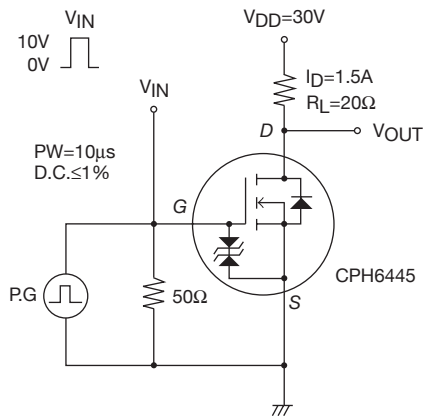
CPH6445

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Drain-to-Source Breakdown Voltage	$V_{(BR)DSS}$	$I_D=1mA, V_{GS}=0V$	60			V
Zero-Gate Voltage Drain Current	I_{DSS}	$V_{DS}=60V, V_{GS}=0V$			1	μA
Gate-to-Source Leakage Current	I_{GSS}	$V_{GS}=\pm 16V, V_{DS}=0V$			± 10	μA
Cutoff Voltage	$V_{GS(off)}$	$V_{DS}=10V, I_D=1mA$	1.2		2.6	V
Forward Transfer Admittance	$ y_{fs} $	$V_{DS}=10V, I_D=1.5A$	1.2	2.0		S
Static Drain-to-Source On-State Resistance	$R_{DS(on)1}$	$I_D=1.5A, V_{GS}=10V$		92	117	$m\Omega$
	$R_{DS(on)2}$	$I_D=0.7A, V_{GS}=4.5V$		120	168	$m\Omega$
	$R_{DS(on)3}$	$I_D=0.7A, V_{GS}=4V$		132	185	$m\Omega$
Input Capacitance	C_{iss}	$V_{DS}=20V, f=1MHz$		310		pF
Output Capacitance	C_{oss}			40		pF
Reverse Transfer Capacitance	C_{rss}			25		pF
Turn-ON Delay Time	$t_{d(on)}$	See specified Test Circuit.		6.0		ns
Rise Time	t_r			5.5		ns
Turn-OFF Delay Time	$t_{d(off)}$			27		ns
Fall Time	t_f			13		ns
Total Gate Charge	Q_g	$V_{DS}=30V, V_{GS}=10V, I_D=3.5A$		6.8		nC
Gate-to-Source Charge	Q_{gs}			1.1		nC
Gate-to-Drain "Miller" Charge	Q_{gd}			1.4		nC
Diode Forward Voltage	V_{SD}	$I_S=3.5A, V_{GS}=0V$		0.85	1.2	V

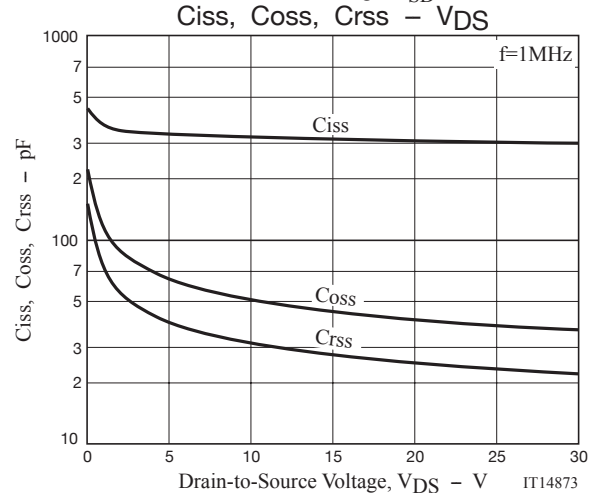
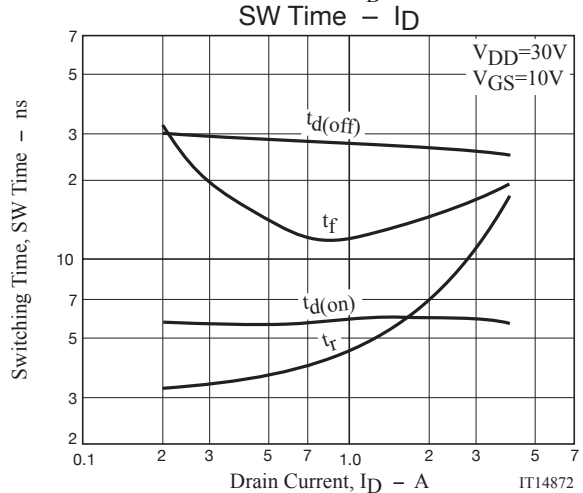
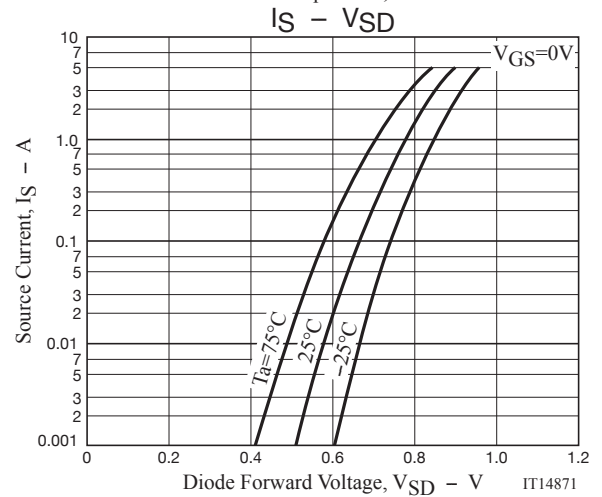
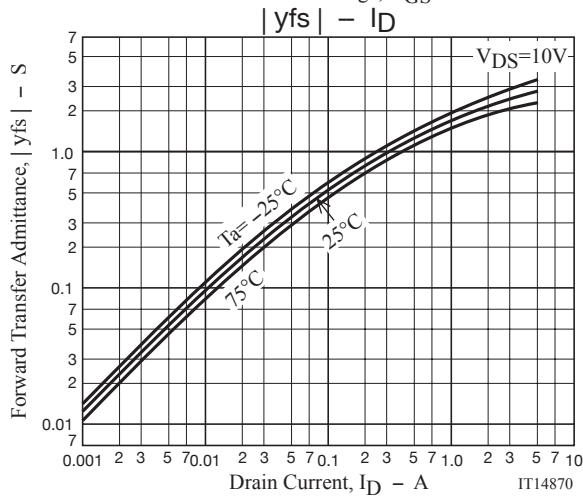
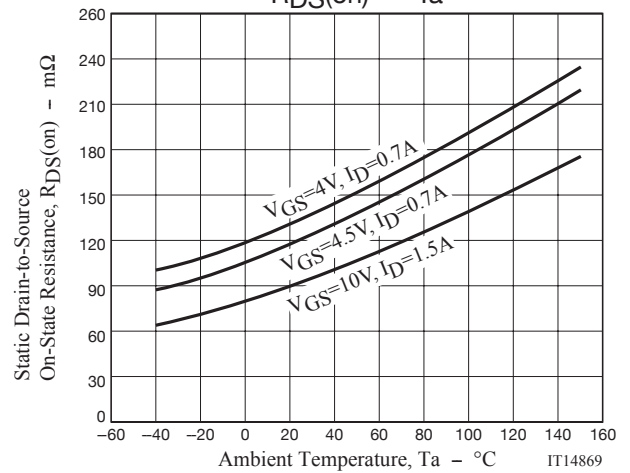
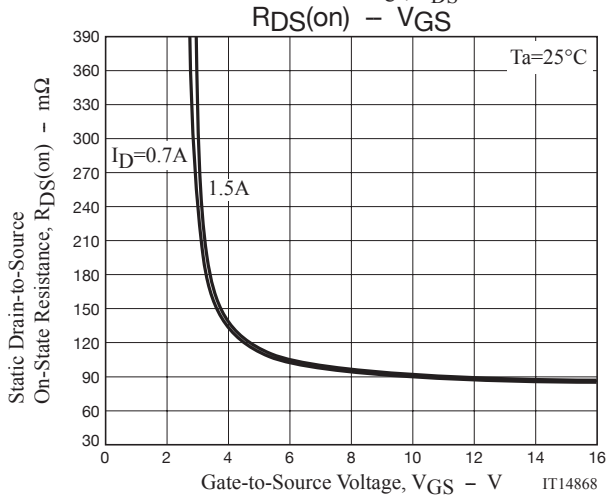
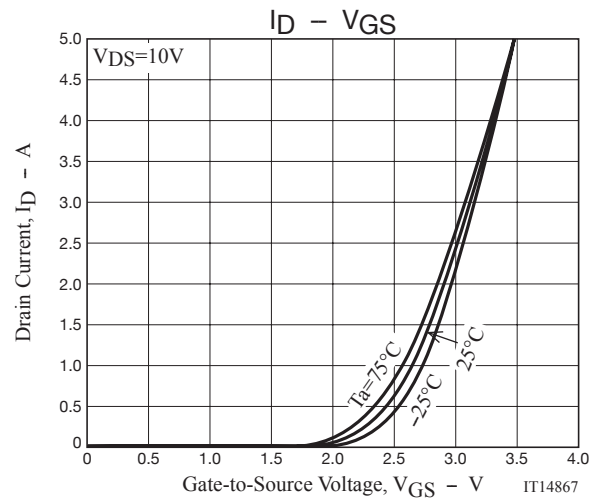
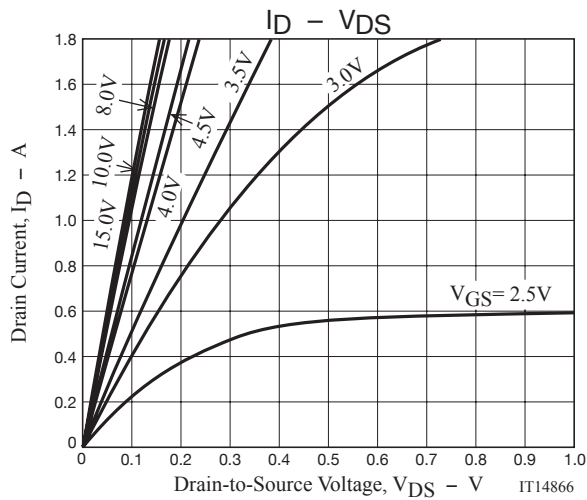
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

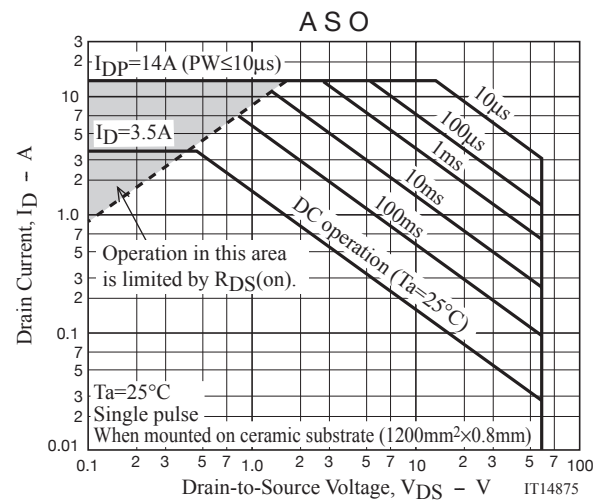
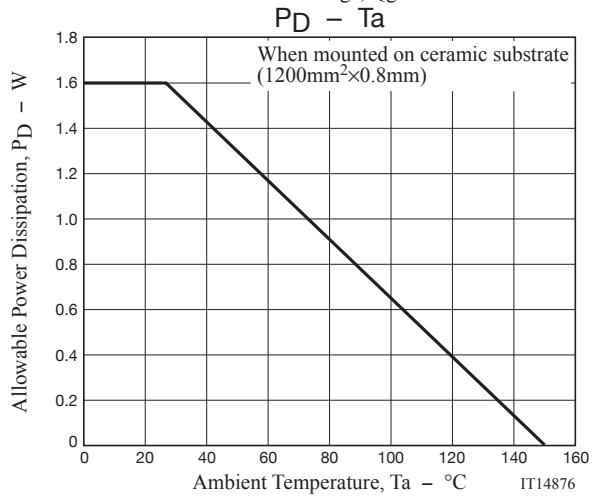
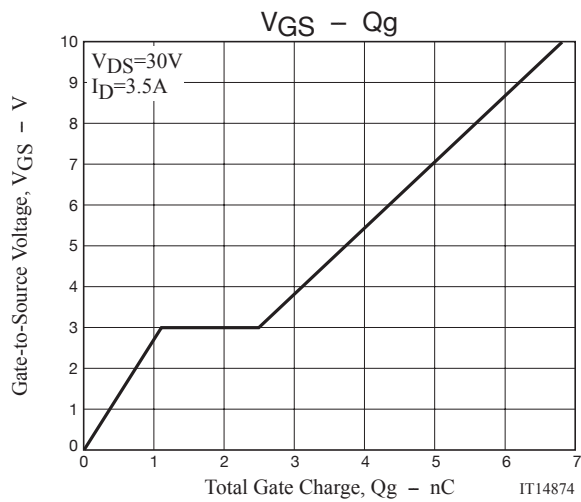
Switching Time Test Circuit



Ordering Information

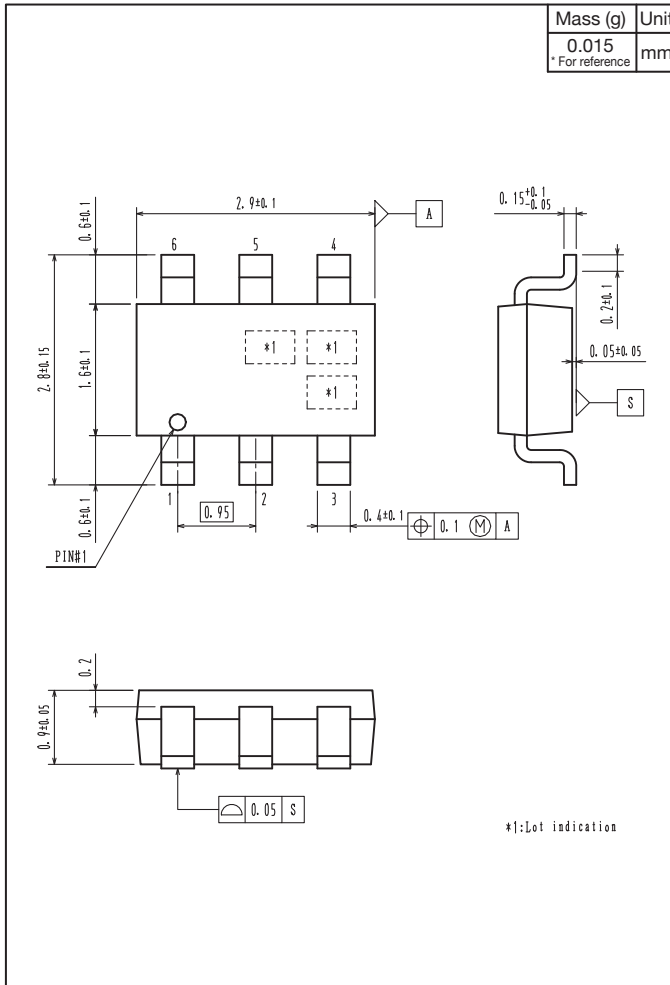
Device	Package	Shipping	memo
CPH6445-TL-E	CPH6	3,000pcs./reel	Pb-Free
CPH6445-TL-W			Pb-Free and Halogen Free



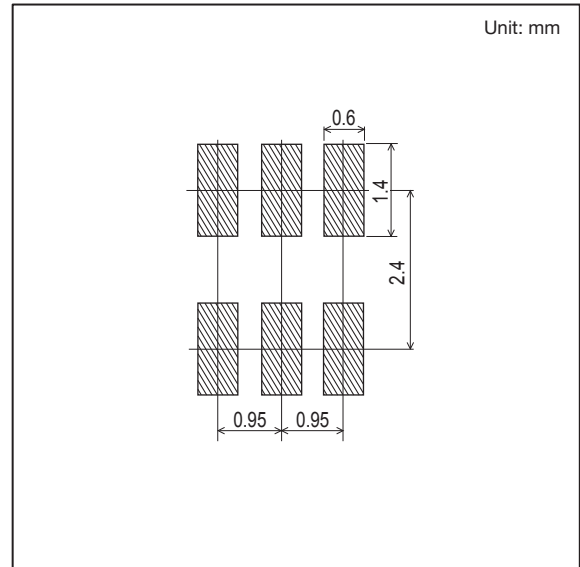


Outline Drawing

CPH6445-TL-E, CPH6445-TL-W



Land Pattern Example



Note on usage : Since the CPH6445 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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